

INCHANGE SEMICONDUCTOR

isc Silicon NPN Darlington Power Transistor

MJE803

2

DESCRIPTION

Collector–Emitter Breakdown Voltage—

: V_{(BR)CEO} = 80 V

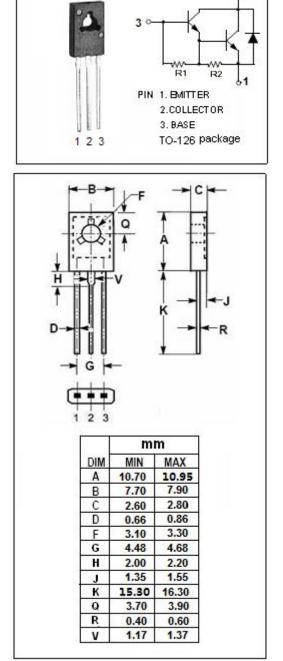
DC Current Gain

: h_{FE} = 750(Min) @ I_C= 2A

- = 100(Min) @ I_C= 4A
- Complement to Type MJE703
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for general-purpose amplifier and low-speed switching applications



ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{сво}	Collector-Base Voltage	80	V
V_{CEO}	Collector-Emitter Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
Ι _C	Collector Current-Continuous	4	А
I _B	Base Current	0.1	А
Pc	Collector Power Dissipation T_c =25°C	40	W
Ti	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.13	°C/W

1



isc Silicon NPN Darlington Power Transistor

MJE803

ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^{\circ}\!\!\!^{\circ}\!\!^{\circ}\!\!^{\circ}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 50mA; I _B = 0	80		V
V _{CE} (sat)-1	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 40mA		2.8	V
V _{CE(sat)} -2	Collector-Emitter Saturation Voltage	I _C = 4A; I _B =-40mA		3.0	V
VBE(on)-1	Base-Emitter On Voltage	I _C = 2A; V _{CE} = 3V		2.5	V
V _{BE} (on)-2	Base-Emitter On Voltage	Ic= 4A; Vc= -3V		3.0	V
I _{CEO}	Collector Cutoff Current	V _{CE} = 80V; I _B = 0		0.1	mA
I _{СВО}	Collector Cutoff Current	V _{CB} = 80V; I _E = 0 V _{CB} = 80V; I _E = 0;T _C = 100℃		0.1 0.5	mA
Іево	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		2.0	mA
h _{FE-1}	DC Current Gain	I _C = 2A ; V _{CE} = 3V	750		
h _{FE-2}	DC Current Gain	I _C = 4A ; V _{CE} = 3V	100		

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

2